DL PACKAGE

(TOP VIEW)

- Nine Single-Ended SCSI Transceiver **Channels With Active Termination**
- **Programmable Drivers Provide Active** Negation (Totem Pole) or Wired-OR (Open **Drain) Outputs**
- 24-mA Current-Mode Active Termination With Common Nine-Channel Bus Enable
- Low Output Capacitance Presented to SCSI Bus, 13.5 pF Typ
- 3.3 V Compatible Logic Inputs Provide Bridge from 3 V Controllers to 5 V SCSI
- Designed to Operate at 10-Million Data Transfers Per Second (Fast-SCSI)
- Controlled Driver Rise and Fall Times 5 ns Min
- **High-Receiver Input-Voltage Hysteresis** 500 mV Typ
- **Receiver Input-Noise Pulse Filter** 5 ns Typ
- **Each Driver and Receiver Meets ANSI** X3.131-1994 (SCSI-2) and the Proposed **SCSI-3 Standards**
- Power-Up/Power-Down Glitch Protection
- High Impedance Driver With V_{CC} at 0 V

description

The SN75LBC968 is a nine-channel transceiver with active termination that drives and receives the signals from the single-ended, parallel data buses such as the Small Computer-Systems

56∏ GND [8B 55 GND TE [2 54 CE GND 3 53 ¶ NC 1A l 1DE/RE 5 52 ∏ NC 2A 51 NC 6 2DE/RE 50**∏** 7B 49 NC 3A l 8 48**∏** 6B 3DE/RE 9 4A [10 47 ¶ NC 4DE/RE [11 46 🛮 5B 45 V_{CC} 12 V_{CC1} L GND **1** 13 44 ∏ GND GND [] 14 43 GND 15 42 GND GND [41 GND GND [] 16 GND [] 17 40 GND 18 39 [] V_{CC} Vcc [19 38**∏** NC 5A 37**∏** 4B 20 5DE/RE 21 36 ∏ NC 6A 35**∏** 3B 22 6DE/RE 23 34 ∏ NC 7A 24 33 7DE/RE П 2В 25 32] NC A8 26 8DE/RE 27 30

NC - No internal connection

28

NC

9B

29

9A

9DE/RE

Interface (SCSI) bus. The features of the line drivers, receivers, and active-termination circuits provide the optimum signal-to-noise ratios for reliable data transmission. Integration of the termination and transceivers in the LinBiCMOS™ process provides the necessary analog-circuit performance, has low quiescent power, and reduces the capacitance presented to the bus over separate termination and I/O circuits.

The transceivers of the SN75LBC968 can be enabled to function as totem-pole or open-drain outputs. The open-drain mode drives the wired-OR lines of SCSI (BSY, SEL, and RST) by inputting the data to the direction control input DE/RE instead of the A input. When driving the data through the A input, the outputs become totem poles and provide active signal negation for a higher voltage level on low-to-high signal transitions on heavily loaded buses. In either mode, the turnon and turnoff output transition times are limited to minimize crosstalk through capacitive coupling to adjacent lines and RF emissions from the cable. The receivers are also designed for optimum analog performance by precisely controlling the input-voltage thresholds, providing wide input-voltage hysteresis and including an input-noise filter. These features significantly increase the likelihood of detecting only the desired data signal and rejecting noise.



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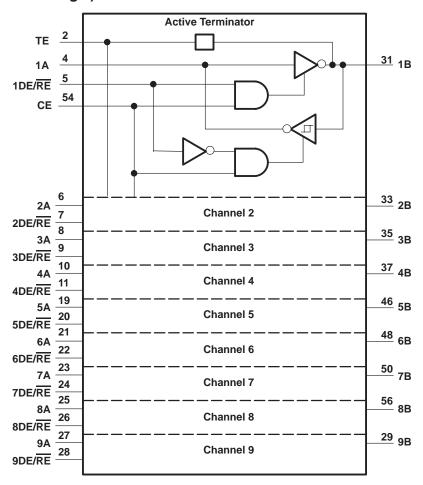
description (continued)

The communication between the SN75LBC968 and the controller can be accomplished at 3.3-V logic levels provided that the $V_{\rm CC1}$ input connects to the same supply rail as the controller. This provides a bridge from the lower-voltage circuit and the 5-V SCSI bus. The SN75LBC968 also removes the need for special I/O buffers (and associated power dissipation) on the controller itself. The SN75LBC968 must be used with a SCSI controller with support for Differential SCSI.

The integrated, current-mode, active termination supplies a constant 24 mA of current (TERMPWR) to the bus when the bus voltage falls below 2.5 V. This makes the next low-to-high (negation) signal transition independent of the low-level (asserted) bus voltage, unlike voltage-mode terminators. The termination current is provided through the TE input and from TERMPWR and can be disabled by letting the TE input float or by connecting it to ground. The termination circuitry is independent from the line drivers and receivers and V_{CC} or V_{CC1} . Operational termination is present as long as TERMPWR is applied.

The switching speeds of the SN75LBC968 are sufficient to transfer data over the data bus at ten million transfers per second (Fast-SCSI). The specification, $t_{sk(lim)}$, is for system skew budgeting and maintenance of bus set-up and hold times. The device is available in the space-efficient shrink-small-outline package (SSOP) with 25-mil lead pitch. The SN75LBC968 meets or exceeds the requirements of ANSI X3.131–1994 (SCSI-2) and the proposed SPI (SCSI-3) standards, and is characterized for operation from 0°C to 70°C.

logic diagram (positive logic)





SN75LBC968 9-CHANNEL BUS TRANSCEIVER WITH ACTIVE TERMINATION SLLS179E - APRIL 1994 - REVISED AUGUST 2005

FUNCTION TABLE

		I	NPUTS			OU	TPUTS
	CE	DE/RE_n	Α	В	TE	Α	В
	L	Х	Х	Х	GND	Z	Z
Terminator	L	Х	Х	Χ	Open	Z	Z
	L	Х	Х	Χ	VTE	Z	–24 mA
	Н	Н	L	NA	GND	Z	Н
	Н	Н	L	NA	Open	Z	Z
Driver	Н	Н	L	NA	VTE	Z	–24 mA
Dilvei	Н	Н	Н	NA	GND	Z	L
	Н	Н	Н	NA	Open	Z	L
	Н	Н	Н	NA	V_{TE}	Z	L
	Н	L	NA	L	GND	Н	Z
	Н	L	NA	L	Open	Н	Z
Danaissan	Н	L	NA	L	V_{TE}	Η	–24 mA
Receiver	Н	L	NA	Н	GND	L	Z
	Н	L	NA	Н	Open	L	Z
	Н	L	NA	Н	VTE	L	–24 mA

NOTE: Input A defaults to a high-level and input B a low-level if left open circuited.

−24 mA = current-mode termination

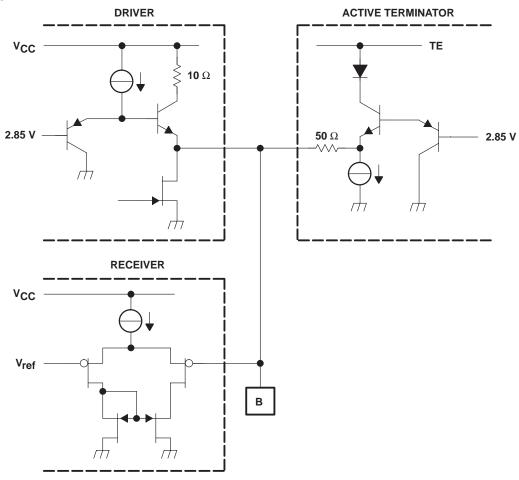
GND = Ground H = High L = LowNA = Not applicable Open = Open circuit $V_{TE} = Termination power$

X = Don't care

Z = High-impedance



schematics



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC} , V _{CC1} , V _{TE} (see Note 1)	
Input voltage range, V _I (A-side)	V _{CC1} + 0.3 V
Bus voltage range (B-side)	–0.5 V to 7 V
Data I/O and control (A-side) voltage range	0.5 V to 7 V
Continuous power dissipation (see Note 2)	Internally Limited
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range, T _{stq}	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



NOTES: 1. All voltage values are with respect to GND.

^{2.} The maximum operating-junction temperature is internally limited. Use the dissipation rating table to operate below this temperature.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25^{\circ}C$ POWER RATING	DERATING FACTOR [†] ABOVE T _A = 25°C	T _A = 70°C POWER RATING
DL	2500 mW	20 mW/°C	1600 mW

[†]Derating factors are the inverse of the junction-to-ambient thermal resistance when board-mounted with no air flow.

recommended operating conditions

				MAX	UNIT
Supply voltage, V _{CC}			5	5.25	V
Supply voltage, V _{CC1} (see Note 3)		3		5.25	V
Termination voltage, VTE		4.25		5.25	V
High-level input voltage, VIH	DE/RE, CE, A, B	2			V
Low-level input voltage, V _{IL}	DE/RE, CE, A, B			0.8	V
High-level output current, I _{OH}	A			-8	mA
	В			48	
Low-level output current, IOL	Α			8	mA
Operating free-air temperature, T _A				70	°C

NOTE 3: All electrical characteristics are measured with $V_{CC1} = V_{CC}$ unless otherwise noted.

driver electrical characteristics over recommended operating conditions (unless otherwise noted) (see Figure 1)

	PARAMETER	TES	MIN	MAX	UNIT	
Vон	High-level output voltage	$I_{OH} = -20 \text{ mA}$		2		V
VOL	Low-level output voltage	I _{OL} = 48 mA			0.5	V
ΙΙΗ	High-level input current	V _{IH} = 2 V,	$V_{CC} = V_{CC1} = 5.25 \text{ V}$		-100	μΑ
I _I L	Low-level input current, A	V _{IL} = 0.5 V,	V _{CC} = V _{CC1} = 5.25 V		-100	μΑ
1	High impedance state output ourrent	$V_0 = 5.25 \text{ V},$	$V_{CC} = V_{CC1} = 5.25 \text{ V}$		-100	
loz	High-impedance-state output current	$V_O = 0 V$	V _{CC} = V _{CC1} = 5.25 V		-100	μΑ

termination electrical characteristics over recommended operating conditions (unless otherwise noted) (see Figure 2)

	PARAMETER	TES	MIN	TYP	MAX	UNIT	
VO(OC)	Open-circuit output voltage	$I_O = 0 \text{ mA},$	$V_{CC} = V_{CC1} = 0 V$	2.5	2.85	3.24	V
	$V_O = 0 V$	$V_{CC} = V_{CC1} = 0 V$			-24	mA	
	Output current	$V_0 = 0.5 V$,	$V_{CC} = V_{CC1} = 0 V$	-20		-24	mA
10	Output current	$V_0 = 3 V$,	$V_{CC} = V_{CC1} = 0 V$			100	μΑ
		V _O = 4 V,	$V_{CC} = V_{CC1} = 0 V$	2		12	mA



SN75LBC968 9-CHANNEL BUS TRANSCEIVER WITH ACTIVE TERMINATION

SLLS179E - APRIL 1994 - REVISED AUGUST 2005

receiver electrical characteristics over recommended operating conditions (unless otherwise noted) (see Figure 3)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Vон	High-level output voltage	$I_{OH} = -8 \text{ mA}$	2	2.5		V
VOL	Low-level output voltage	I _{OL} = 8 mA			8.0	V
V _{IT+}	Positive-going input threshold voltage			1.6	2	V
V_{IT-}	Negative-going input threshold voltage	VCC = VCC1	0.8	1.1	1.4	V
V _{hys}	Input hysteresis voltage (V _{IT+} – V _{IT-})		0.2	0.5		V
lιΗ	High-level input current	V _{IH} = 2 V			100	μΑ
IլL	Low-level input current	V _{IL} = 0.5 V			100	μΑ
lo=	High impedance state output ourrent	VO = 0 V	·		-100	
loz	High-impedance-state output current	V _O = 5.25 V			-100	μΑ

device electrical characteristics over recommended operating conditions (unless otherwise noted)

	PA	RAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
		All drivers, receivers, and terminator disabled	All inputs at 0 V		1.3	3	
.	Supply current to V _{CC}	All receivers enabled, termination and drivers disabled, No load	CE at V_{CC} , DE/ \overline{RE} at 0 V, TE at 0 V		14	21	
ICC	and V _{CC1}	All drivers enabled, termination and			33	45	mA
		receivers disabled, No load	DE/RE and CE at V _{CC} , V _{TE} = 0 V, A at V _{CC1}		15	21	
ICC	Supply current to TE	Termination and receivers enabled, No load	TE at V _{TE} , DE/RE at 0 V		33	45	
Co	Bus port capacitance (se	ee Note 4)			13.5	16.5	pF
lн	High-level input current	DE/RE, CE	V _{IH} = V _{CC} or 2 V			100	μΑ
IIL	Low-level input current	DE/RE, CE	V _{IL} = 0.5 V			100	μΑ

[†] All typical values are at $V_{CC} = V_{CC1} = 5$ V, $T_A = 25$ °C. NOTE 4: Tested in accordance with Annex G X3T9.2/855D, revision 14



driver switching characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	R TEST CONDITIONS			TYP†	MAX	UNIT
t _{PHL}	Propagation delay time, high- to low-level output (see Figure 4)	0 45 5		10		35	ns
tPLH	Propagation delay time, low- to high-level output (see Figure 4)	C _L = 15 pF	15		45	ns	
	Skew limit [‡] , the maximum delay time – minimum delay	$V_{CC} = V_{CC1} = 5 \text{ V}, T_A = 25^{\circ}\text{C}, C_L = 15 \text{ pF}$				14	ns
^t sk(lim)	time	$V_{CC} = V_{CC1} = 5 \text{ V},$ $C_L = 15 \text{ pF}$	$T_A = 70^{\circ}C,$	70°C,		14	ns
tsk(p)	Pulse skew, tpHL - tpLH	V _{CC} = V _{CC1} = 5 V, T _A = 25°C			8		ns
t _t	Output transition time, 10% to 90% or 90% to 10% of the steady-state output	15 pF < C _L < 100 pF		5		20	ns
	Propagation delay time, low-level to high-impedance	From CE,	C _L = 15 pF	5		150	
^t PLZ		From DE/RE,	C _L = 15 pF			45 ns	
+	Propagation delay time, high-impedance to low-level	From CE, C _L = 15 pF 5 1		150	20		
^t PZL	output (see Figure 5)	From DE/RE,	C _L = 15 pF			45	ns

[†] All typical values are at $V_{CC} = V_{CC1} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

receiver switching characteristics over recommended of operating conditions (unless otherwise noted)

	PARAMETER	TEST COND	ITIONS	MIN	TYP [†]	MAX	UNIT	
tPHL	Propagation delay time, high- to low-level output	0 5: 0		5		20	ns	
tPLH	Propagation delay time, low- to high-level output	See Figure 6		5		25	ns	
	Skew limit‡, the maximum delay time – minimum delay	$V_{CC} = V_{CC1} = 5 \text{ V},$ See Figure 6	$T_A = 25^{\circ}C$,			8.5	ns	
^t sk(lim)	time	$V_{CC} = V_{CC1} = 5 \text{ V},$ See Figure 6	$T_A = 70^{\circ}C$,			8.5	ns	
t _{sk(p)}	Pulse skew, tpHL - tpLH	V _{CC} = V _{CC1} = 5 V, See Figure 6	T _A = 25°C,		6		ns	
	Propagation delay time, low-level to high-impedance	From CE,	See Figure 7	5		150		
^t PLZ	output	From DE/RE,	See Figure 7			45	ns	
	Propagation delay time, high-impedance to low-level	From CE,	See Figure 7	5		150		
tPZL	output	From DE/RE,	See Figure 7			80	ns	
	Propagation delay time, high-level to high-impedance	From CE,	See Figure 8	5		150		
^t PHZ	output	From DE/RE,	See Figure 8			45	ns	
	Propagation delay time, high-impedance to high-level	From CE,	See Figure 8	5	5			
^t PZH	output	From DE/RE,	See Figure 8			80	ns	

[†] All typical values are at $V_{CC} = V_{CC1} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

thermal characteristics

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$R_{\theta JA}$	Junction-to-free-air thermal resistance	Board-mounted, no air flow		50		°C/W
$R_{\theta JC}$	Junction-to-case thermal resistance			12		°C/W
TJS	Junction-shutdown temperature			180		°C



[‡] The value for this parameter was derived from the difference between the slowest and the fastest driver delay times measured on devices from four sample wafer lots.

[‡] The value for this parameter was derived from the difference between the slowest and the fastest driver delay times measured on devices from four sample wafer lots.

PARAMETER MEASUREMENT INFORMATION

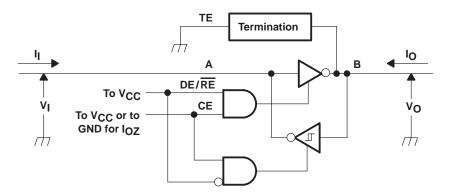


Figure 1. Driver Test Circuit Currents and Voltages.

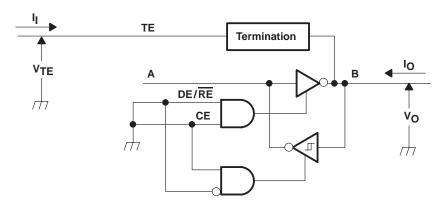


Figure 2. Active Termination Voltages, Currents, and Test Circuit.

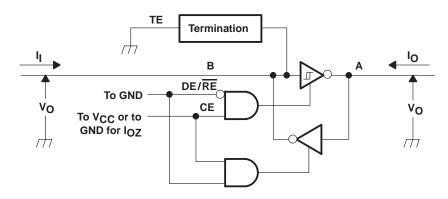
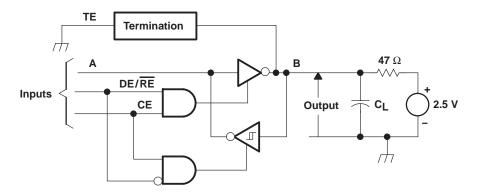


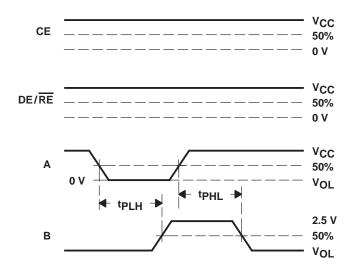
Figure 3. Receiver Voltages, Currents, and Test Circuit

- NOTES: A. All input pulses are supplied by a generator having the following characteristics: $t_{\Gamma} \le 6$ ns, $t_{f} \le 6$ ns, PRR ≤ 1 MHz, duty cycle = 50%, Z_{O} = 50 Ω .
 - B. All resistances are in ohms and $\pm 5\%$, unless otherwise indicated.
 - C. All capacitances are in picofarads and $\pm 10\%$, unless otherwise indicated.
 - D. All indicated voltages are ± 10 mV.



PARAMETER MEASUREMENT INFORMATION





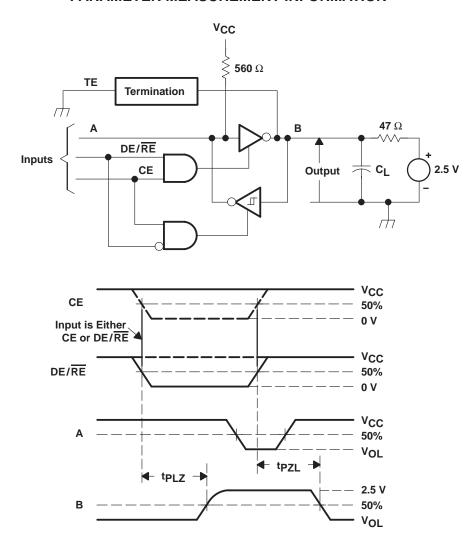
NOTES: A. All input pulses are supplied by a generator having the following characteristics: $t_f \le 6$ ns, $t_f \le 6$ ns, PRR ≤ 1 MHz, duty cycle = 50%, $Z_O = 50$ Ω .

- B. All resistances are in ohms and $\pm 5\%$, unless otherwise indicated.
- C. All capacitances are in picofarads and $\pm\,10\%$, unless otherwise indicated.
- D. All indicated voltages are ± 10 mV.

Figure 4. Driver Delay Time Test Circuit and Waveforms



PARAMETER MEASUREMENT INFORMATION

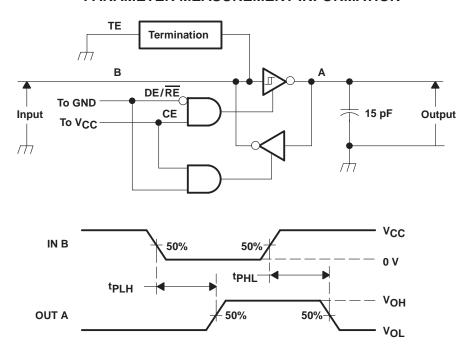


- NOTES: A. All input pulses are supplied by a generator having the following characteristics: $t_f \le 6$ ns, $t_f \le 6$ ns, PRR ≤ 1 MHz, duty cycle = 50%, $Z_O = 50$ Ω .
 - B. All resistances are in ohms and $\pm 5\%$, unless otherwise indicated.
 - C. All capacitances are in picofarads and $\pm 10\%$, unless otherwise indicated.
 - D. All indicated voltages are ± 10 mV.

Figure 5. Driver Delay Time Test Circuit and Waveforms



PARAMETER MEASUREMENT INFORMATION



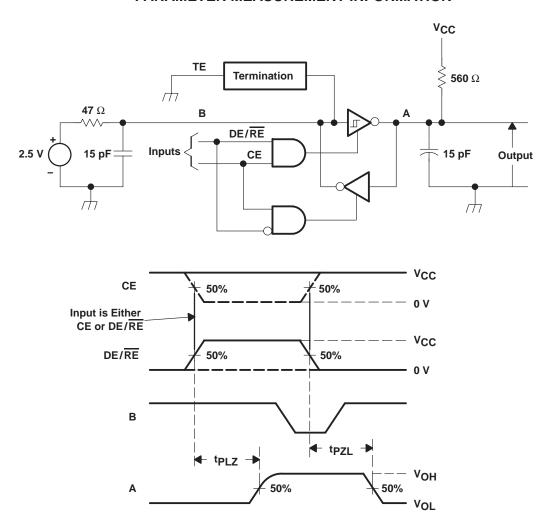
NOTES: A. All input pulses are supplied by a generator having the following characteristics: $t_{\Gamma} \leq$ 6 ns, $t_{f} \leq$ 6 ns, PRR \leq 1 MHz, duty cycle = 50%, Z_{O} = 50 Ω .

- B. All resistances are in ohms and $\pm 5\%$, unless otherwise indicated.
- C. All capacitances are in picofarads and $\pm 10\%$, unless otherwise indicated.
- D. All indicated voltages are ± 10 mV.

Figure 6. Receiver Propagation Delay Time Test Circuit and Waveforms



PARAMETER MEASUREMENT INFORMATION



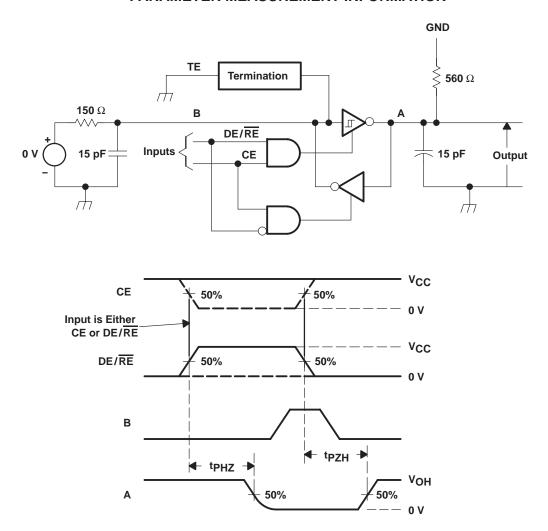
NOTES: A. All input pulses are supplied by a generator having the following characteristics: $t_{\text{f}} \leq 6$ ns, $t_{\text{f}} \leq 6$ ns, PRR ≤ 1 MHz, duty cycle = 50%, $Z_{\text{O}} = 50~\Omega$.

- B. All resistances are in ohms and $\pm 5\%$, unless otherwise indicated.
- C. All capacitances are in picofarads and $\pm 10\%$, unless otherwise indicated.
- D. All indicated voltages are ± 10 mV.

Figure 7. Receiver Enable and Disable Times to and From Low-Level Output Test Circuit and Waveforms



PARAMETER MEASUREMENT INFORMATION



- NOTES: A. All input pulses are supplied by a generator having the following characteristics: $t_f \le 6$ ns, $t_f \le 6$ ns, PRR ≤ 1 MHz, duty cycle = 50%, $Z_O = 50~\Omega$.
 - B. All resistances are in ohms and $\pm 5\%$, unless otherwise indicated.
 - C. All capacitances are in picofarads and $\pm 10\%$, unless otherwise indicated.
 - D. All indicated voltages are ± 10 mV.

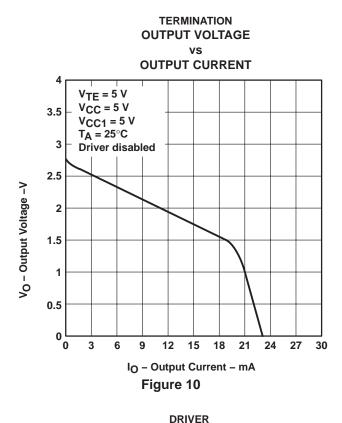
Figure 8. Receiver Enable and Disable Times to and From High-Level Output Test Circuit and Waveforms

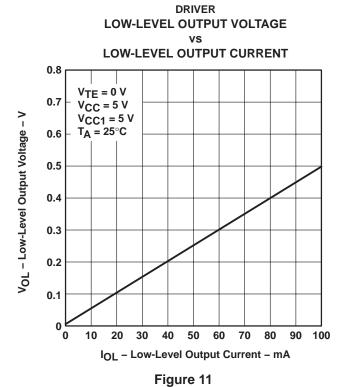


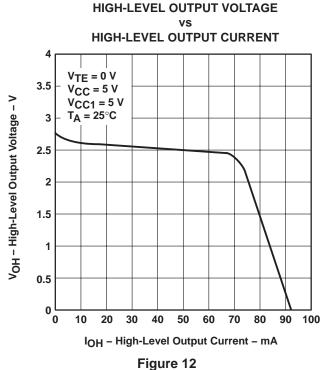
TYPICAL CHARACTERISTICS

DRIVER AND TERMINATION LOW-LEVEL OUTPUT VOLTAGE vs LOW-LEVEL OUTPUT CURRENT 0.9 **V_{TE}** = 5 V V_{CC} = 5 V 0.8 V_{CC1} = 5 V V_{OL} - Low-Level Output Voltage - V T_A = 25°C 0.7 0.6 0.5 0.4 0.3 0.2 0.1 40 50 60 70 IOL - Low-Level Output Current - mA

Figure 9

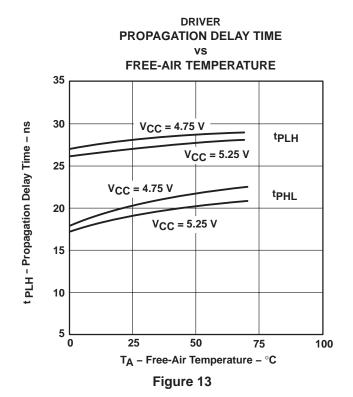


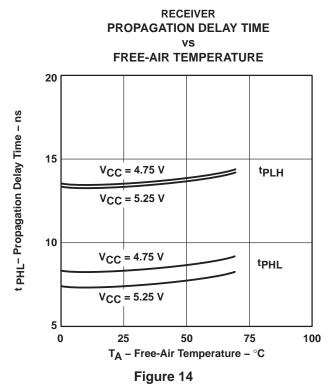






TYPICAL CHARACTERISTICS











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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN75LBC968DL	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN75LBC968DLG4	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN75LBC968DLR	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN75LBC968DLRG4	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75LBC968DLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75LBC968DLR	SSOP	DL	56	1000	346.0	346.0	49.0

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